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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
10/750,310	12/31/2003	Colin John Dickinson	M02A296	9706	
20411 THE BOC GRO	7590 12/21/200 DUP, INC.	5	EXAM	INER	
575 MOUNTA	IN ÁVENUE	•	ZERVIGON, RUDY		
MURKAY HIL	L, NJ 07974-2064		ART UNIT PAPER NUMBER		
			1763		
SHORTENED STATUTOR	Y PERIOD OF RESPONSE	MAIL DATE	DELIVERY MODE		
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Please find below and/or attached an Office communication concerning this application or proceeding.

If NO period for reply is specified above, the maximum statutory period will apply and will expire 6 MONTHS from the mailing date of this communication.

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	Application No.	Applicant(s)				
	10/750,310	DICKINSON, COLIN JOH	N			
Office Action Summary	Examiner	Art Unit				
	Rudy Zervigon	1763				
The MAILING DATE of this communication apperiod for Reply	pears on the cover sheet with	the correspondence address				
A SHORTENED STATUTORY PERIOD FOR REPL WHICHEVER IS LONGER, FROM THE MAILING D - Extensions of time may be available under the provisions of 37 CFR 1. after SIX (6) MONTHS from the mailing date of this communication. - If NO period for reply is specified above, the maximum statutory period - Failure to reply within the set or extended period for reply will, by statute Any reply received by the Office later than three months after the mailin earned patent term adjustment. See 37 CFR 1.704(b).	ATE OF THIS COMMUNICA 136(a). In no event, however, may a rep will apply and will expire SIX (6) MONTH e, cause the application to become ABAI	ATION. ly be timely filed IS from the mailing date of this communicat NDONED (35 U.S.C. § 133).				
Status						
1) Responsive to communication(s) filed on 23 C	October 2006.					
	s action is non-final.					
3) Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.						
Disposition of Claims	·					
 4) Claim(s) 1-21 is/are pending in the application 4a) Of the above claim(s) 10-21 is/are withdray 5) Claim(s) is/are allowed. 6) Claim(s) 1-9 is/are rejected. 7) Claim(s) is/are objected to. 8) Claim(s) are subject to restriction and/or 	wn from consideration.					
Application Papers						
9) The specification is objected to by the Examine	er.					
10)☐ The drawing(s) filed on is/are: a)☐ accepted or b)☐ objected to by the Examiner.						
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).						
Replacement drawing sheet(s) including the correct 11) The oath or declaration is objected to by the Ex	•	- n	• •			
Priority under 35 U.S.C. § 119						
12) Acknowledgment is made of a claim for foreign a) All b) Some * c) None of: 1. Certified copies of the priority document 2. Certified copies of the priority document 3. Copies of the certified copies of the priority application from the International Burea * See the attached detailed Office action for a list	ts have been received. ts have been received in Apprintly documents have been re u (PCT Rule 17.2(a)).	olication No eceived in this National Stage				
Attachment(s) 1) Notice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawing Review (PTO-948) 3) Information Disclosure Statement(s) (PTO/SB/08) Paper No(s)/Mail Date	Paper No(s)/	mmary (PTO-413) Mail Date rmal Patent Application				

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DETAILED ACTION

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Election/Restrictions

1. Applicant's election of Group I, claims 1-9 in the reply filed on October 23, 2006 is acknowledged. Because applicant did not distinctly and specifically point out the supposed errors in the restriction requirement, the election has been treated as an election without traverse (MPEP § 818.03(a)).

Double Patenting

2. The nonstatutory double patenting rejection is based on a judicially created doctrine grounded in public policy (a policy reflected in the statute) so as to prevent the unjustified or improper timewise extension of the "right to exclude" granted by a patent and to prevent possible harassment by multiple assignees. A nonstatutory obviousness-type double patenting rejection is appropriate where the conflicting claims are not identical, but at least one examined application claim is not patentably distinct from the reference claim(s) because the examined application claim is either anticipated by, or would have been obvious over, the reference claim(s). See, e.g., In re Berg, 140 F.3d 1428, 46 USPQ2d 1226 (Fed. Cir. 1998); In re Goodman, 11 F.3d 1046, 29 USPQ2d 2010 (Fed. Cir. 1993); In re Longi, 759 F.2d 887, 225 USPQ 645 (Fed. Cir. 1985); In re Van Ornum, 686 F.2d 937, 214 USPQ 761 (CCPA 1982); In re Vogel, 422 F.2d 438, 164 USPQ 619 (CCPA 1970); and In re Thorington, 418 F.2d 528, 163 USPQ 644 (CCPA 1969).

A timely filed terminal disclaimer in compliance with 37 CFR 1.321(c) or 1.321(d) may be used to overcome an actual or provisional rejection based on a nonstatutory double patenting ground provided the conflicting application or patent either is shown to be commonly owned with this application, or claims an invention made as a result of activities undertaken within the scope of a joint research agreement.

Effective January 1, 1994, a registered attorney or agent of record may sign a terminal disclaimer. A terminal disclaimer signed by the assignee must fully comply with 37 CFR 3.73(b).

3. Claims 1-9 are rejected on the ground of nonstatutory obviousness-type double patenting as being unpatentable over claims 1-120 of U.S. Patent No. 6701972 B2 in view of Spencer; John E. et al. (US 4657618 A). Although the conflicting claims are not identical, they are not patentably distinct from each other because the claims of the present invention do not claim a controller to selectively control. Spencer teaches a control system (10; Figure 9) for gas precursor delivery.

It would have been obvious to one of ordinary skill in the art at the time the invention was made to add Spencer's controller to the apparatus of U.S. Patent No. 6701972 B2.

Motivation to to add Spencer's controller to the apparatus of U.S. Patent No. 6701972 B2 is for coordinating precursor gas injection as taught by Spencer (column 9, line 61 – column 10, line 23).

Claim Rejections - 35 USC § 112

4. The following is a quotation of the second paragraph of 35 U.S.C. 112:

The specification shall conclude with one or more claims particularly pointing out and distinctly claiming the subject matter which the applicant regards as his invention.

- 5. Claims 1-9 are rejected under 35 U.S.C. 112, second paragraph, as being indefinite for failing to particularly point out and distinctly claim the subject matter which applicant regards as the invention.
- 6. Claim 1 recites the limitation "said first precursor valve", and "said second precursor valve". There is insufficient antecedent basis for this limitation in the claim.

Claim Rejections - 35 USC § 102

7. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.

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8. Claims 1-4, and 9 are rejected under 35 U.S.C. 102(e) as being clearly anticipated by Moriya, Shuji et al. (US 20040112289 A1). Moriya teaches an atomic layer deposition arrangement (Figure 1,2; [0009], [0032]) comprising: a process reactor chamber (50; Figure 1,2; [0009], [0032]) including an inlet (150; Figure 2; [0009], [0032], not numbered, Figure 1) for receiving precursor gases (10-40; Figure 1,2; [0009], [0032]) and at least one outlet (141; Figure 2; [0009], [0032]; not numbered, Figure 1) coupled through an outlet (141; Figure 2; [0009], [0032]; not numbered, Figure 1) line to an exhaust (140; Figure 2; [0009], [0032]; 60, Figure 1), a first precursor gas valve (12/22; Figure 1; 80; Figure 2) which receives a first precursor gas (10/20; Figure 1; 90; Figure 2), said first precursor gas valve (12/22; Figure 1; 80; Figure 2) coupled to said inlet (150; Figure 2; [0009], [0032], not numbered, Figure 1), a second precursor gas valve (32/42; Figure 1; 110; Figure 2) which receives a second precursor gas (30/40; Figure 1; 40; Figure 2), said second precursor gas valve (32/42; Figure 1; 110; Figure 2) coupled to said inlet (150; Figure 2; [0009], [0032], not numbered, Figure 1), a first bypass conduit (91; Figure 2; 11/21; Figure 1) coupled to said first precursor valve (12/22; Figure 1; 80; Figure 2), a second bypass conduit (121; Figure 2; 31/41; Figure 1) coupled to said second precursor valve (32/42; Figure 1; 110; Figure 2), and wherein said first bypass conduit (91; Figure 2; 11/21; Figure 1) and said second bypass conduit (121; Figure 2; 31/41; Figure 1) are isolated from the outlet (141; Figure 2; [0009], [0032]; not numbered, Figure 1) line, as claimed by claim 1

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i. An atomic layer deposition arrangement (Figure 1,2; [0009], [0032]) according to claim 1 wherein the first precursor gas valve (12/22; Figure 1; 80; Figure 2) and second precursor gas valve (32/42; Figure 1; 110; Figure 2) are each three way valves (Figure 2 embodiment), as claimed by claim 2

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ii. An atomic layer deposition arrangement (Figure 1,2; [0009], [0032]) according to claim 1 wherein the first precursor gas valve (12/22; Figure 1; 80; Figure 2) and second precursor gas valve (32/42; Figure 1; 110; Figure 2) each include two two-way valves (Figure 1 embodiment), as claimed by claim 3

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- iii. An atomic layer deposition arrangement (Figure 1,2; [0009], [0032]) according to claim 1 wherein the first bypass conduit (91; Figure 2; 11/21; Figure 1) and the second bypass conduit (121; Figure 2; 31/41; Figure 1) are isolated from each other, as claimed by claim 4
- An atomic layer deposition arrangement (Figure 1,2; [0009], [0032]) according to claim 1 iv. further comprising a valve (22/32; Figure 1,2) which receives a purge gas, said valve coupled to the inlet (150; Figure 2; [0009], [0032], not numbered, Figure 1) to the process reactor chamber (50; Figure 1,2; [0009], [0032]), as claimed by claim 9

Claim Rejections - 35 USC § 103

- 9. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 10. Claims 5-8 are rejected under 35 U.S.C. 103(a) as being unpatentable over Moriya, Shuji et al. (US 20040112289 A1) in view of Murakami; Satoshi et al. (US 5431738 A). Moriya is discussed above.

Moriya does not teach:

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i. An atomic layer deposition arrangement (Figure 1,2; [0009], [0032]) according to claim 1 further comprising a substrate holding device located in the process chamber (50; Figure 1,2; [0009], [0032]), the substrate holding device movable in a longitudinal direction, as claimed by claim 5

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- ii. An atomic layer deposition arrangement (Figure 1,2; [0009], [0032]) according to claim 1 wherein the chamber (50; Figure 1,2; [0009], [0032]) includes a sub-chamber (50; Figure 1,2; [0009], [0032]) and wherein the at least one outlet (141; Figure 2; [0009], [0032]; not numbered, Figure 1) is located in the sub-chamber (50; Figure 1,2; [0009], [0032]), as claimed by claim 6
- iii. An atomic layer deposition arrangement (Figure 1,2; [0009], [0032]) according to claim 5 wherein the substrate holding device comprises a vacuum hold down system, as claimed by claim 7
- iv. An atomic layer deposition arrangement (Figure 1,2; [0009], [0032]) according to claim 7 wherein the vacuum hold down system includes a hollow shaft connected to a plate member having at least one through hole, as claimed by claim 8

Murakami teaches a deposition apparatus (Figure 7) including:

- v. a substrate holding device (2; Figure 5-7; column 4; lines 30-50; column 5, line 51-column 6, line 35) located in the process chamber (1; Figure 7; column 4; lines 30-50), the substrate holding device (2; Figure 5-7; column 4; lines 30-50; column 5, line 51-column 6, line 35) movable in a longitudinal direction, as claimed by claim 5
- vi. the chamber (1; Figure 7; column 4; lines 30-50) includes a sub-chamber (below 6; Figure 7; column 4; lines 30-50) and wherein the at least one outlet (16; Figure 7; column

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4; lines 30-50) is located in the sub-chamber (below 6; Figure 7; column 4; lines 30-50), as claimed by claim 6

- vii. the substrate holding device (2; Figure 5-7; column 4; lines 30-50; column 5, line 51-column 6, line 35) comprises a vacuum hold down system (7; Figure 7), as claimed by claim 7
- viii. wherein the vacuum hold down system (7; Figure 7) includes a hollow shaft (7; Figure 7) connected to a plate member (6; Figure 7) having at least one through hole, as claimed by claim 8

It would have been obvious to one of ordinary skill in the art at the time the invention was made to add Murakami's substrate holding device to Moriya's apparatus.

Motivation to add Murakami's substrate holding device to Moriya's apparatus is for achieveing the required thickness of the deposited film as taught by Moriya (column 7, lines 30-32).

Conclusion

11. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Examiner Rudy Zervigon whose telephone number is (571) 272-1442. The examiner can normally be reached on a Monday through Thursday schedule from 8am through 7pm. The official fax phone number for the 1763 art unit is (571) 273-8300. Any Inquiry of a general nature or relating to the status of this application or proceeding should be directed to the Chemical and Materials Engineering art unit receptionist at (571) 272-1700. If the examiner can not be reached please contact the examiner's supervisor, Parviz Hassanzadeh, at (571) 272-1435.